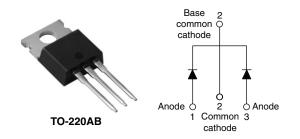
Vishay High Power Products

Schottky Rectifier, 2 x 15 A

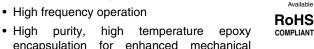


SHA

PRODUCT SUMMARY				
I _{F(AV)}	2 x 15 A			
V _R	25/30 V			

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- · High frequency operation



- encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- · Designed and qualified for industrial level

DESCRIPTION

The 32CTQ...PbF Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	30	A		
V _{RRM}		25/30	V		
I _{FSM}	$t_p = 5 \ \mu s \ sine$	900	A		
V _F	15 Apk, T _J = 125 °C	0.40	V		
TJ	Range	- 55 to 150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	32CTQ025PbF	32CTQ030PbF	UNITS
Maximum DC reverse voltage	V _R	25	30	V
Maximum working peak reverse voltage	V _{RWM}	25	30	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 115 °C, rectangular waveform		30	
Maximum peak one cycle non-repetitive surge current	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900	A	
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	250	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1.20 \text{ A}, L = 11.10 \text{ mH}$		13	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А

* Pb containing terminations are not RoHS compliant, exemptions may apply

32CTQ...PbF

Vishay High Power Products Schottky Rectifier, 2 x 15 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	15 A	T _J = 25 °C	0.49	v
		30 A		0.58	
		15 A	T _J = 125 °C	0.40	
		30 A		0.53	
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1.75	mA
See fig. 2	IRM (")	T _J = 125 °C		97	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		0.233	V
Forward slope resistance	r _t			9.09	mΩ
Maximum junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		1300	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

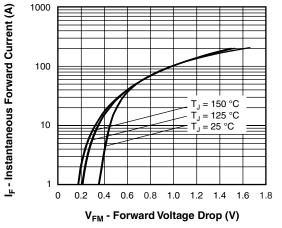
Note

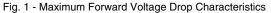
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECH	THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and sto temperature range	rage	T _J , T _{Stg}		- 55 to 150	°C	
Maximum thermal resistan junction to case per leg	ce,	R _{thJC}	DC operation See fig. 4	3.25	°C/W	
Typical thermal resistance case to heatsink	,	R _{thCS}	Mounting surface, smooth and greased	0.50		
				2	g	
Approximate weight			0.07	0Z.		
Mounting torque ——	minimum			6 (5)	kgf ⋅ cm	
	maximum			12 (10)	(lbf · in)	
Marking device				32CT	Q025	
			Case style TO-220AB	32CT	32CTQ030	



Schottky Rectifier, 2 x 15 A Vishay High Power Products





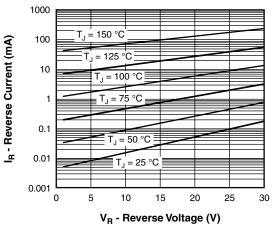


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

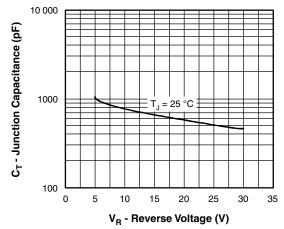


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

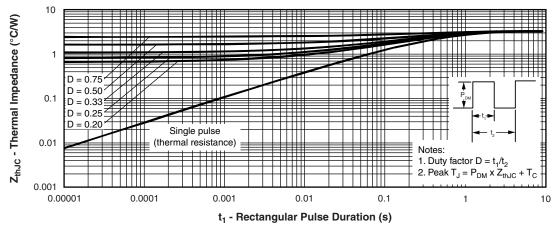
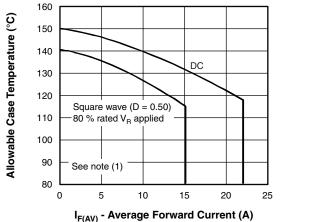
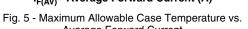


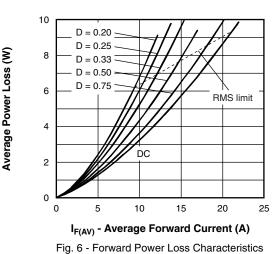
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

32CTQ...PbF

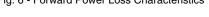
Vishay High Power Products Schottky Rectifier, 2 x 15 A

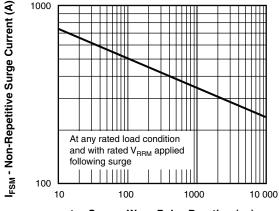






Average Forward Current





t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

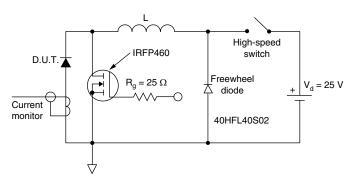


Fig. 8 - Unclamped Inductive Test Circuit

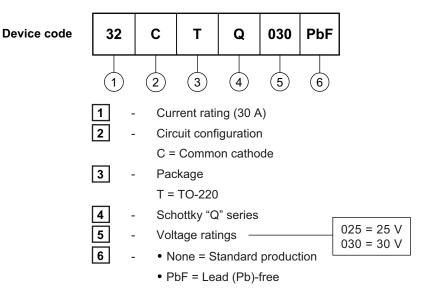
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = 80 \% rated V_R$



Schottky Rectifier, 2 x 15 A Vishay High Power Products

ORDERING INFORMATION TABLE



Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95222					
Part marking information	http://www.vishay.com/doc?95225				



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.